

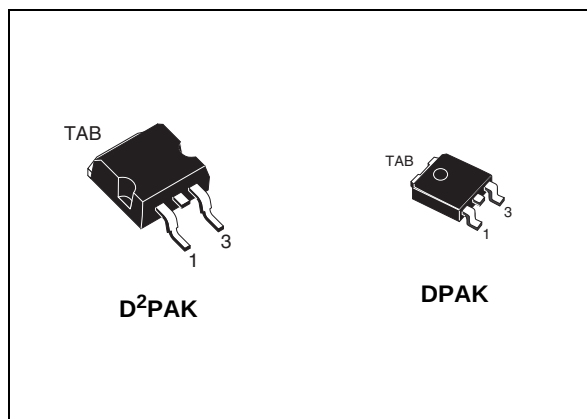
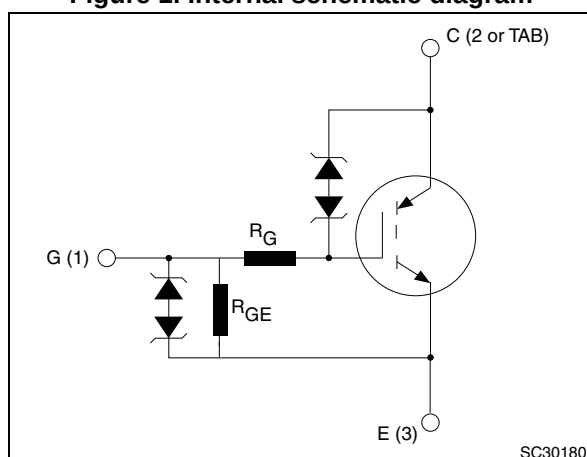


Figure 1. Internal schematic diagram



Features

- Designed for automotive applications and AEQ-Q101 qualified
- ESD gate-emitter protection
- Gate-collector high voltage clamping
- Logic level gate drive
- Low saturation voltage
- High pulsed current capability
- Gate and gate-emitter resistor

Applications

- Pencil coil electronic ignition driver

Description

This application-specific IGBT utilizes the most advanced PowerMESH™ technology. The built-in Zener diodes between gate-collector and gate-emitter provide overvoltage protection capabilities. The device also exhibits low on-state voltage drop and low threshold drive for use in automotive ignition systems.

Table 1. Device summary

Order codes	Marking	Packages	Packaging
STGB20N40LZT4	GB20N40LZ	D ² PAK	Tape and reel
STGD20N40LZT4	GD20N40LZ	DPAK	Tape and reel

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1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value		Unit
		DPAK	D ² PAK	
V_{CES}	Collector-emitter voltage ($V_{GE} = 0$)	$V_{CES(clamped)}$		V
V_{ECS}	Emitter collector voltage ($V_{GE} = 0$)	20		V
I_C	Collector current (continuous) at $T_C = 100\text{ }^{\circ}\text{C}$	25		A
$I_{CP}^{(1)}$	Pulsed collector current	40		A
V_{GE}	Gate-emitter voltage	$V_{GE(clamped)}$		V
P_{TOT}	Total dissipation at $T_C = 25\text{ }^{\circ}\text{C}$	125	150	W
E_{AS}	Single pulse energy $T_C = 25\text{ }^{\circ}\text{C}$, $L = 3\text{ mH}$, $V_{CC} = 50\text{ V}$	300		mJ
E_{AS}	Single pulse energy $T_C = 150\text{ }^{\circ}\text{C}$, $L = 3\text{ mH}$, $V_{CC} = 50\text{ V}$	180		mJ
ESD	Human body model, $R = 1.5\text{ k}\Omega$, $C = 100\text{ pF}$	8		kV
	Machine model, $R = 0$, $C = 100\text{ pF}$	600		V
	Charged device model	4		kV
T_{stg}	Storage temperature	– 55 to 175		$^{\circ}\text{C}$
T_J	Operating junction temperature			

1. Pulse width limited by maximum junction temperature.

Table 3. Thermal data

Symbol	Parameter	Value		Unit
		DPAK	D ² PAK	
$R_{thj-case}$	Thermal resistance junction-case	1.2	1	$^{\circ}\text{C/W}$
$R_{thj-amb}$	Thermal resistance junction-ambient	100	62.5	$^{\circ}\text{C/W}$

2 Electrical characteristics

$T_J = 25\text{ °C}$ unless otherwise specified.

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{CES(clamped)}$	Collector emitter clamped voltage ($V_{GE} = 0$)	$I_C = 2\text{ mA}$		390		V
		$I_C = 2\text{ mA}$, $T_J = -40\text{ °C}$ to 175 °C	365		425	V
$V_{(BR)ECS}$	Emitter collector break-down voltage ($V_{GE} = 0$)	$I_C = 75\text{ mA}$ $T_J = -40\text{ °C}$ to 175 °C	20	28		V
$V_{GE(clamped)}$	Gate emitter clamped voltage	$I_G = \pm 2\text{ mA}$ $T_J = -40\text{ °C}$ to 175 °C	10		16	V
I_{CES}	Collector cut-off current ($V_{GE} = 0$)	$V_{CE} = 15\text{ V}$, $T_J = 175\text{ °C}$			20	μA
		$V_{CE} = 200\text{ V}$, $T_J = 175\text{ °C}$			100	μA
I_{GES}	Gate-emitter leakage current ($V_{CE} = 0$)	$V_{GE} = \pm 10\text{ V}$		625		μA
		$V_{GE} = \pm 10\text{ V}$ $T_J = -40\text{ °C}$ to 175 °C	450		900	μA
R_{GE}	Gate emitter resistance		11	16	22	$\text{k}\Omega$
R_G	Gate resistance			100		Ω
$V_{GE(th)}$	Gate threshold voltage	$V_{GE} = V_{CE}$, $I_C = 1\text{ mA}$	1.5	1.95	2.5	V
		$V_{GE} = V_{CE}$, $I_C = 1\text{ mA}$, $T_J = 175\text{ °C}$	0.85	1.3	1.7	V
$V_{CE(sat)}$	Collector emitter saturation voltage	$V_{GE} = 4.5\text{ V}$, $I_C = 10\text{ A}$, $T_J = 175\text{ °C}$		1.5	1.8	V
		$V_{GE} = 4\text{ V}$, $I_C = 6\text{ A}$,		1.30	1.6	V

Table 5. Dynamic electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
C_{ies}	Input capacitance	$V_{CE} = 25\text{ V}$, $f = 1\text{ MHz}$, $V_{GE} = 0$	-	910	-	pF
C_{oes}	Output capacitance		-	70	-	pF
C_{res}	Reverse transfer capacitance		-	10	-	pF
Q_g	Gate charge	$V_{CE} = 280\text{ V}$, $I_C = 10\text{ A}$, $V_{GE} = 5\text{ V}$	-	24	-	nC

Table 6. Switching on/off

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$ t_r	Resistive load Turn-on delay time Rise time	$V_{CC} = 14\text{ V}$, $R_g = 1\text{ k}\Omega$, $R_L = 1\ \Omega$, $V_{GE} = 5\text{ V}$	-	0.7 4	-	μs μs
$t_{d(on)}$ t_r	Resistive load Turn-on delay time Rise time	$V_{CC} = 14\text{ V}$, $R_g = 1\text{ k}\Omega$, $R_L = 1\ \Omega$, $V_{GE} = 5\text{ V}$, $T_J = 150\text{ }^\circ\text{C}$	-	0.7 4.5	-	μs μs
$t_{d(off)}$ t_f dv/dt	Inductive load Turn-off delay time Fall time Turn-off voltage slope	$V_{CC} = 300\text{ V}$, $L = 1\text{ mH}$ $I_C = 10\text{ A}$, $V_{GE} = 5\text{ V}$, $R_g = 1\text{ k}\Omega$	-	4.3 1.5 165	-	μs μs $\text{V}/\mu\text{s}$
$t_{d(off)}$ t_f dv/dt	Inductive load Turn-off delay time Fall time Turn-off voltage slope	$V_{CC} = 300\text{ V}$, $L = 1\text{ mH}$ $I_C = 10\text{ A}$, $V_{GE} = 5\text{ V}$, $R_g = 1\text{ k}\Omega$, $T_J = 150\text{ }^\circ\text{C}$	-	4.7 3.5 115	-	μs μs $\text{V}/\mu\text{s}$

2.1 Electrical characteristics (curves)

Figure 2. Collector-emitter on voltage vs temperature ($V_{ge}=4.5\text{ V}$)

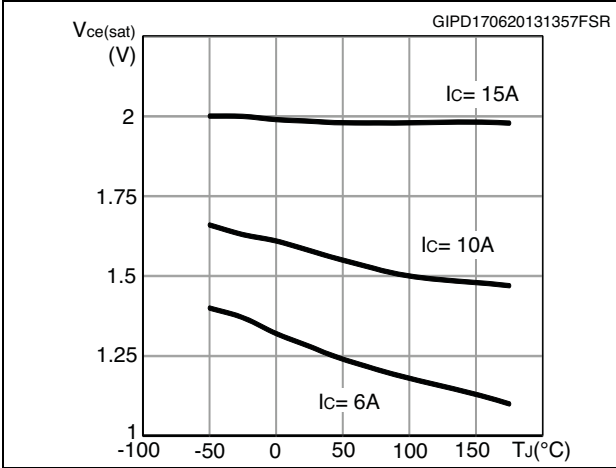


Figure 3. Collector-emitter on voltage vs temperature ($I_C=6\text{ A}$)

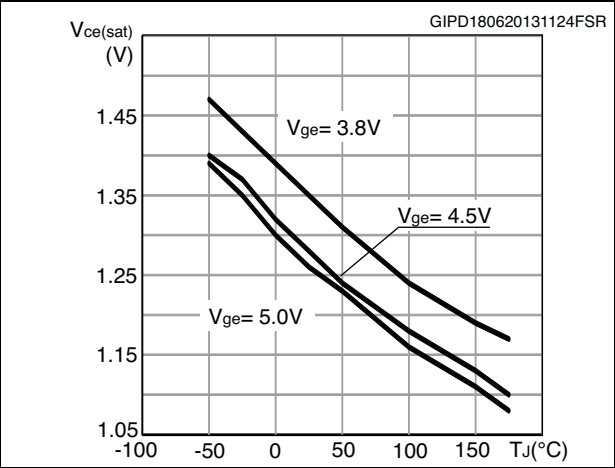


Figure 4. Collector-emitter on voltage vs temperature ($I_C=10\text{ A}$)

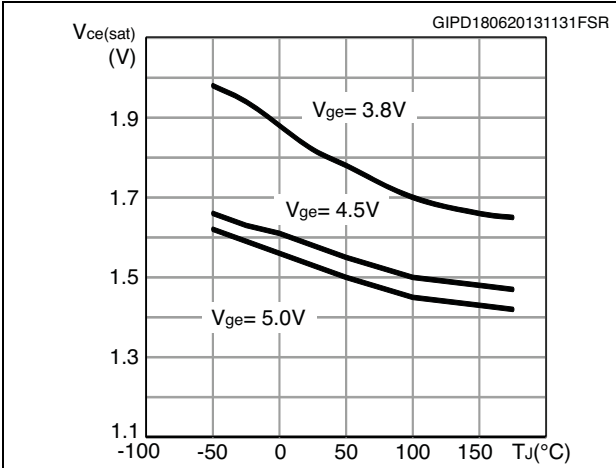


Figure 5. Self clamped inductive switch

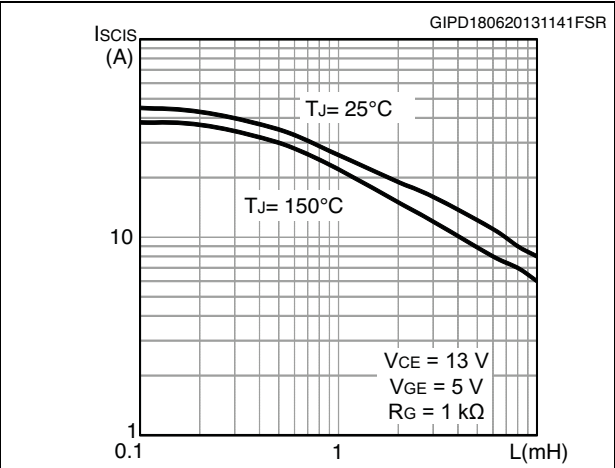


Figure 6. Output characteristics ($T_J = 25^\circ\text{C}$)

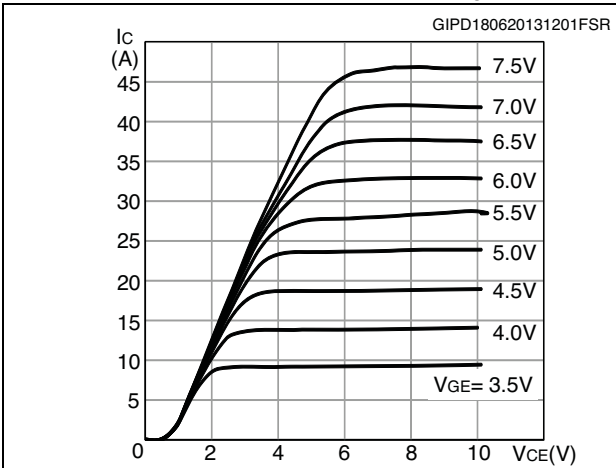


Figure 7. Output characteristics ($T_J = -40^\circ\text{C}$)

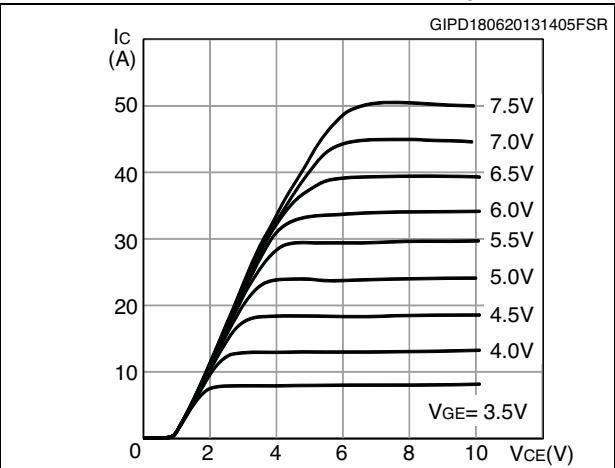


Figure 8. Output characteristics ($T_J = 175^\circ\text{C}$)

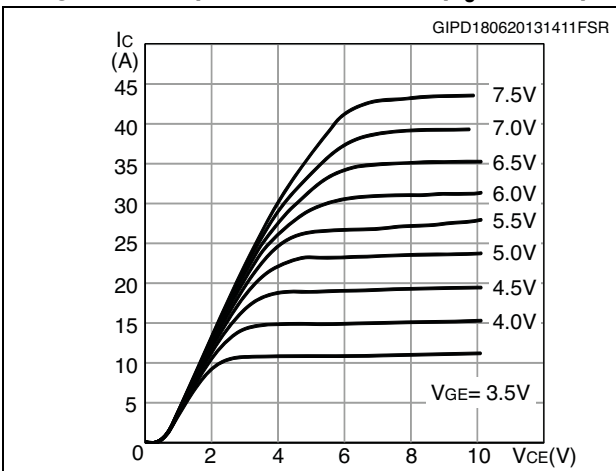


Figure 9. Transfer characteristics

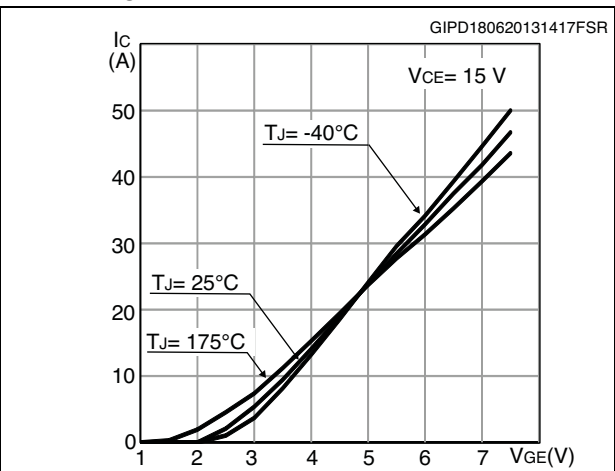


Figure 10. Collector cut-off current vs. temperature

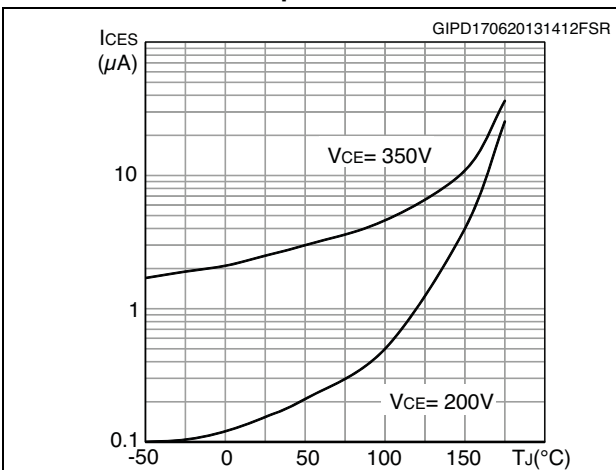


Figure 11. Normalized collector emitter voltage vs temperature

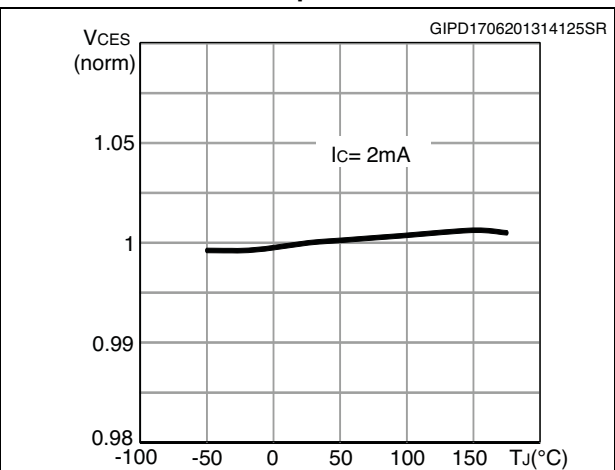


Figure 12. Normalized gate threshold voltage vs temperature

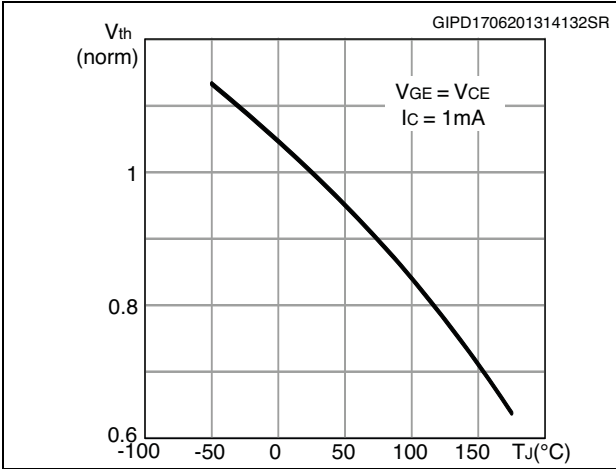


Figure 13. Normalized collector emitter on-voltage vs temperature

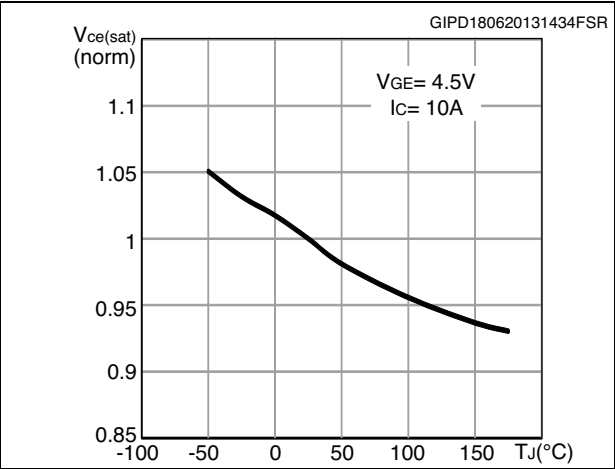


Figure 14. Thermal impedance for D²PAK

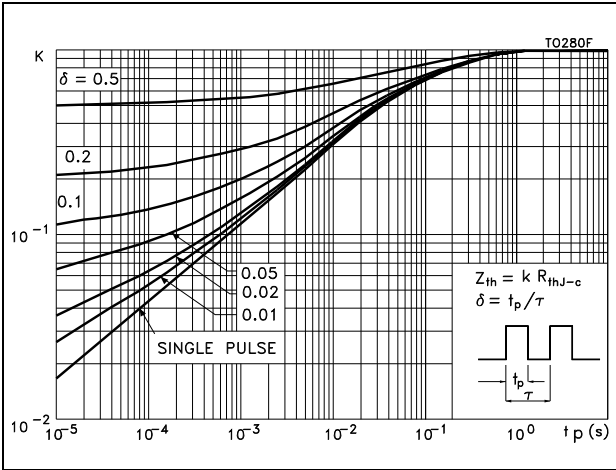
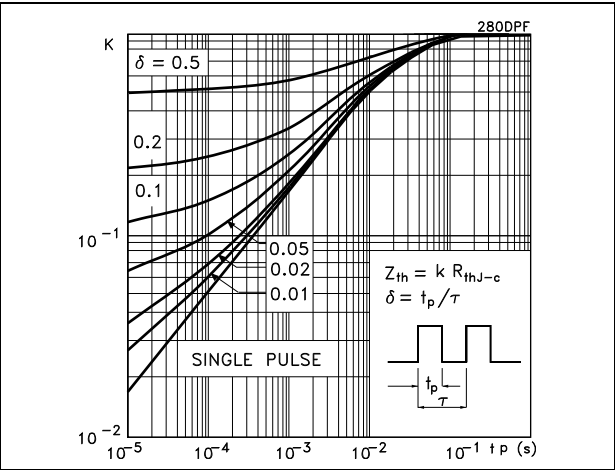


Figure 15. Thermal impedance for DPAK



3 Test circuits

Figure 16. Inductive load switching

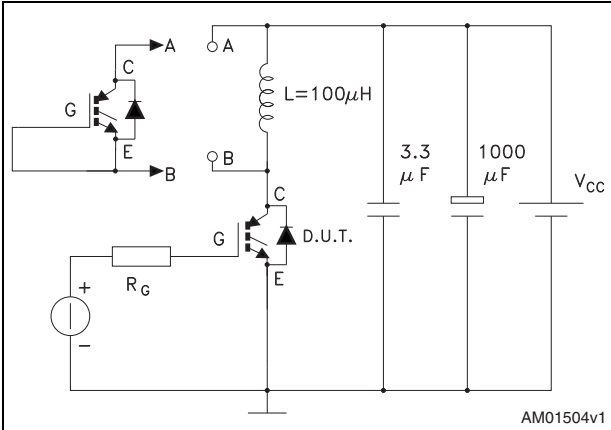


Figure 17. Resistive load switching

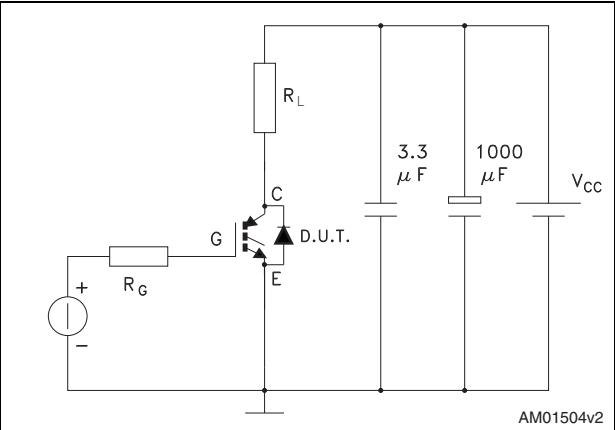


Figure 18. Gate charge test circuit

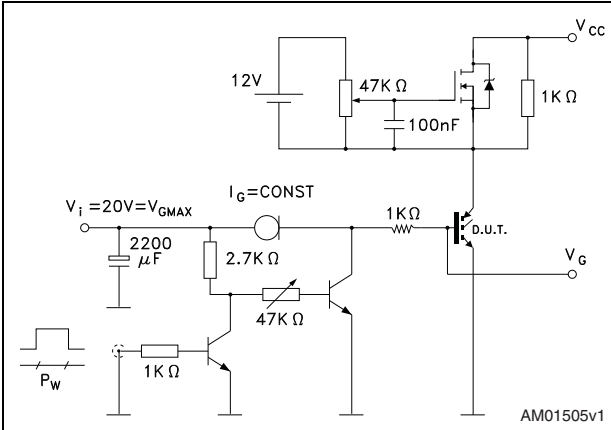
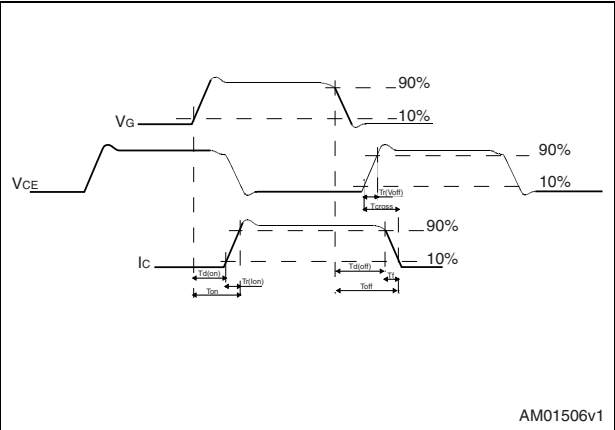


Figure 19. Switching waveform

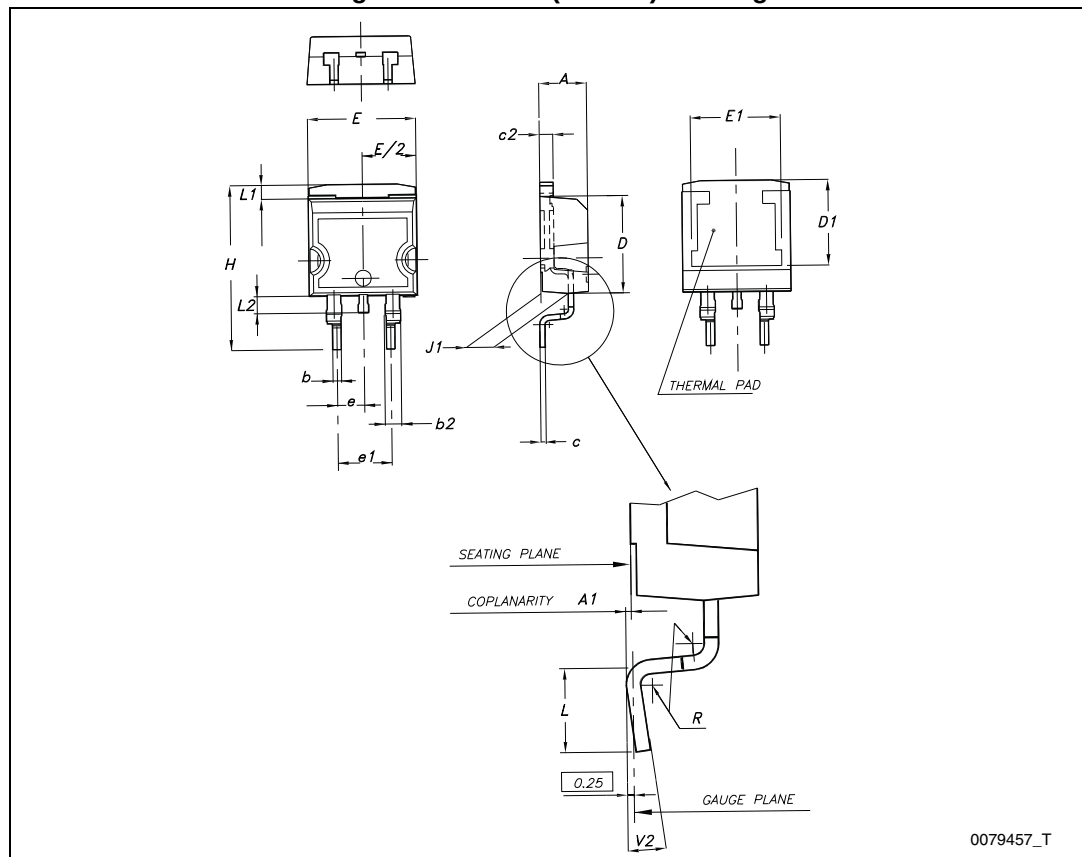
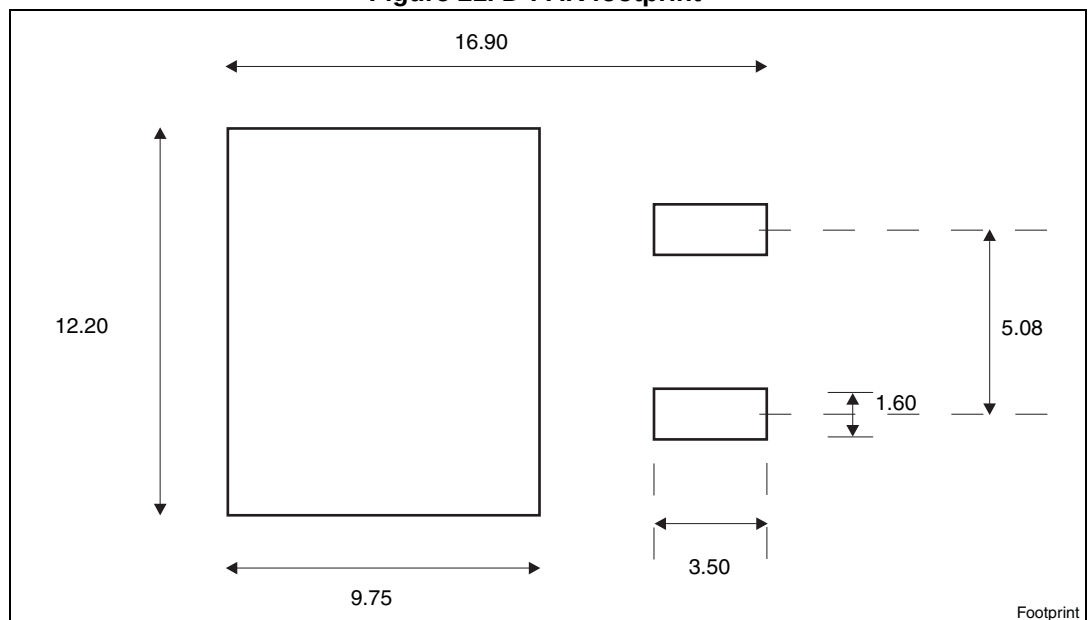


4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 7. D²PAK (TO-263) mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.40		4.60
A1	0.03		0.23
b	0.70		0.93
b2	1.14		1.70
c	0.45		0.60
c2	1.23		1.36
D	8.95		9.35
D1	7.50		
E	10		10.40
E1	8.50		
e		2.54	
e1	4.88		5.28
H	15		15.85
J1	2.49		2.69
L	2.29		2.79
L1	1.27		1.40
L2	1.30		1.75
R		0.4	
V2	0°		8°

Figure 20. D²PAK (TO-263) drawingFigure 21. D²PAK footprint^(a)

a. All dimension are in millimeters

Table 8. DPAK (TO-252) type A mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
c	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
e		2.28	
e1	4.40		4.60
H	9.35		10.10
L	1.00		1.50
(L1)		2.80	
L2		0.80	
L4	0.60		1.00
R		0.20	
V2	0°		8°

Figure 22. DPAK (TO-252) type A drawing

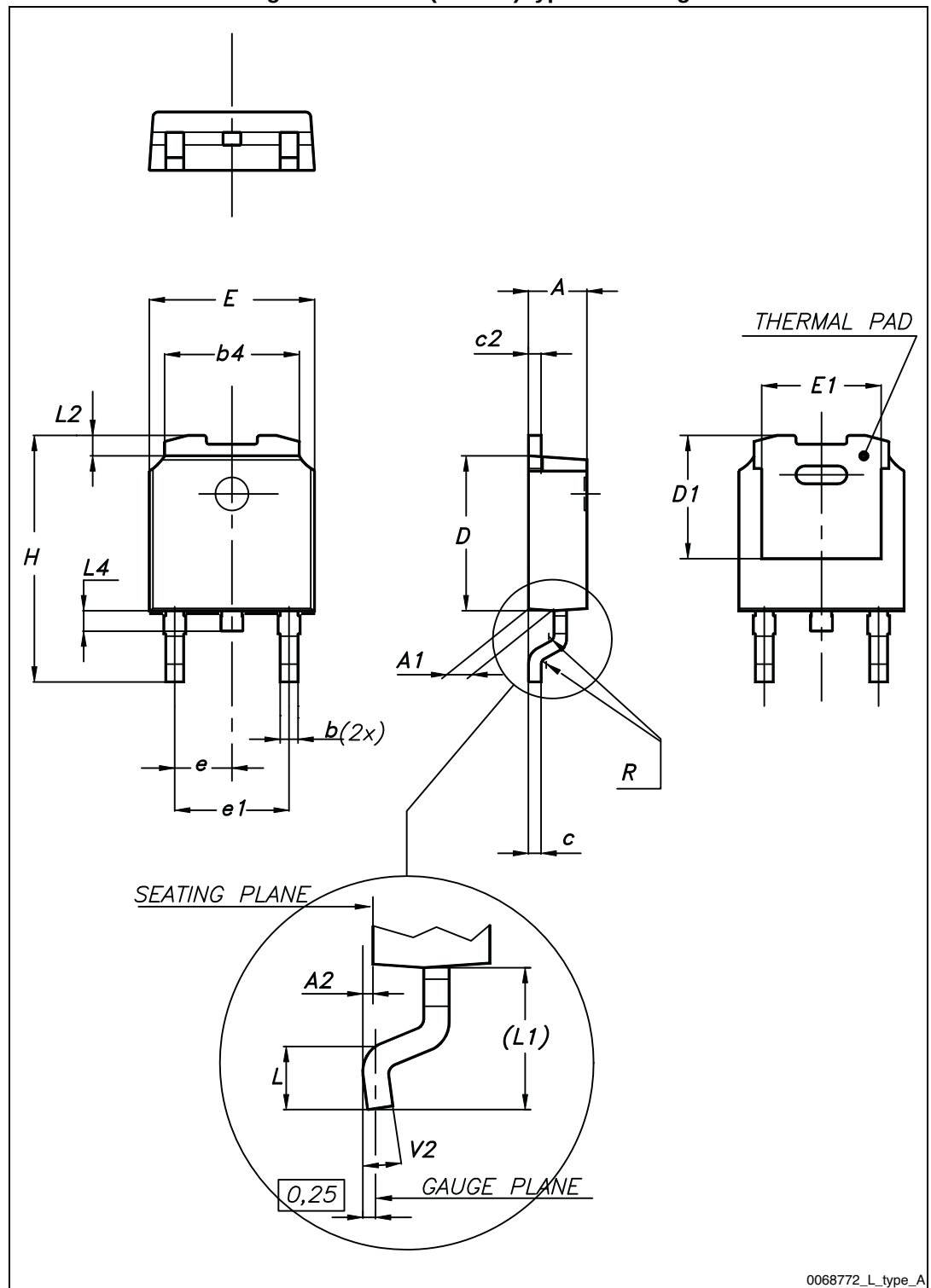
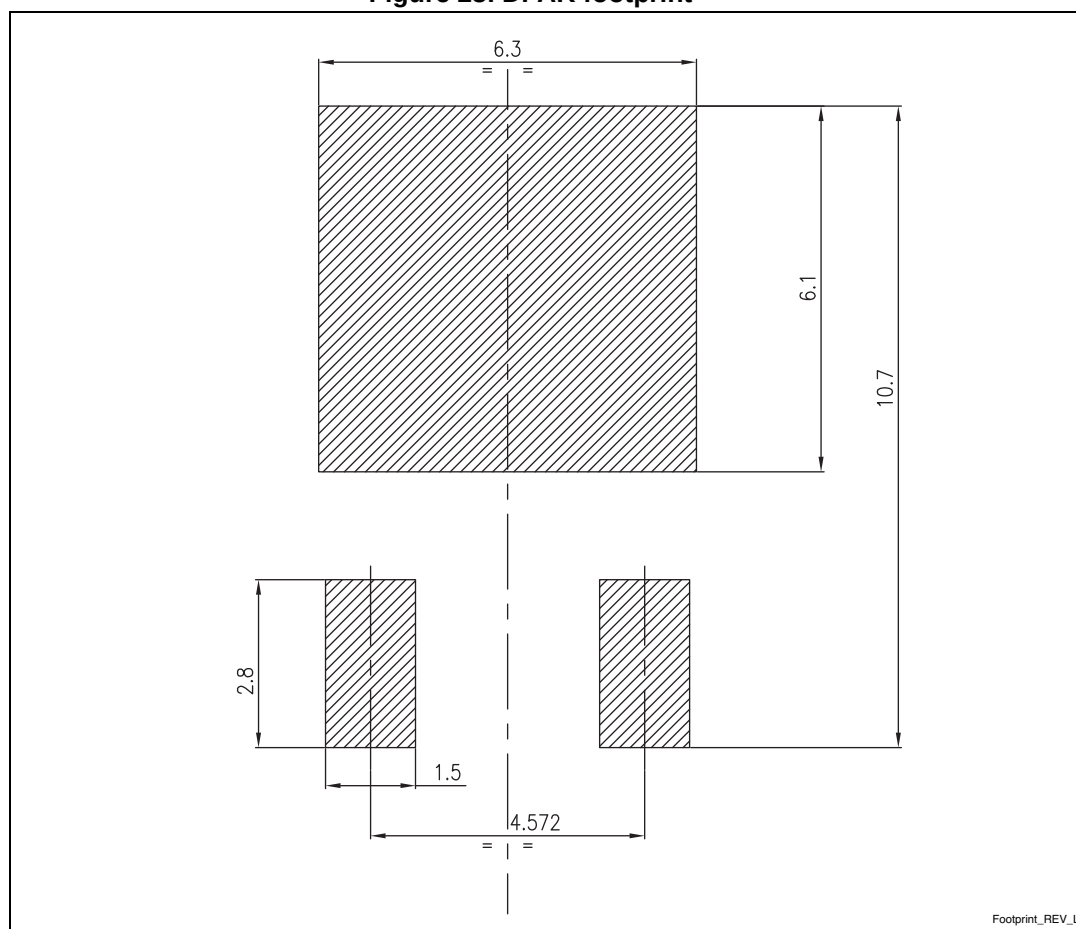


Figure 23. DPAK footprint (b)



b. All dimensions are in millimeters

5 Packaging mechanical data

Table 9. D²PAK (TO-263) tape and reel mechanical data

Tape			Reel		
Dim.	mm		Dim.	mm	
	Min.	Max.		Min.	Max.
A0	10.5	10.7	A		330
B0	15.7	15.9	B	1.5	
D	1.5	1.6	C	12.8	13.2
D1	1.59	1.61	D	20.2	
E	1.65	1.85	G	24.4	26.4
F	11.4	11.6	N	100	
K0	4.8	5.0	T		30.4
P0	3.9	4.1			
P1	11.9	12.1	Base qty		1000
P2	1.9	2.1	Bulk qty		1000
R	50				
T	0.25	0.35			
W	23.7	24.3			

Table 10. DPAK (TO-252) tape and reel mechanical data

Tape			Reel		
Dim.	mm		Dim.	mm	
	Min.	Max.		Min.	Max.
A0	6.8	7	A		330
B0	10.4	10.6	B	1.5	
B1		12.1	C	12.8	13.2
D	1.5	1.6	D	20.2	
D1	1.5		G	16.4	18.4
E	1.65	1.85	N	50	
F	7.4	7.6	T		22.4
K0	2.55	2.75			
P0	3.9	4.1	Base qty.		2500
P1	7.9	8.1	Bulk qty.		2500

Table 10. DPAK (TO-252) tape and reel mechanical data (continued)

Tape			Reel		
Dim.	mm		Dim.	mm	
	Min.	Max.		Min.	Max.
P2	1.9	2.1			
R	40				
T	0.25	0.35			
W	15.7	16.3			

Figure 24. Tape drawing

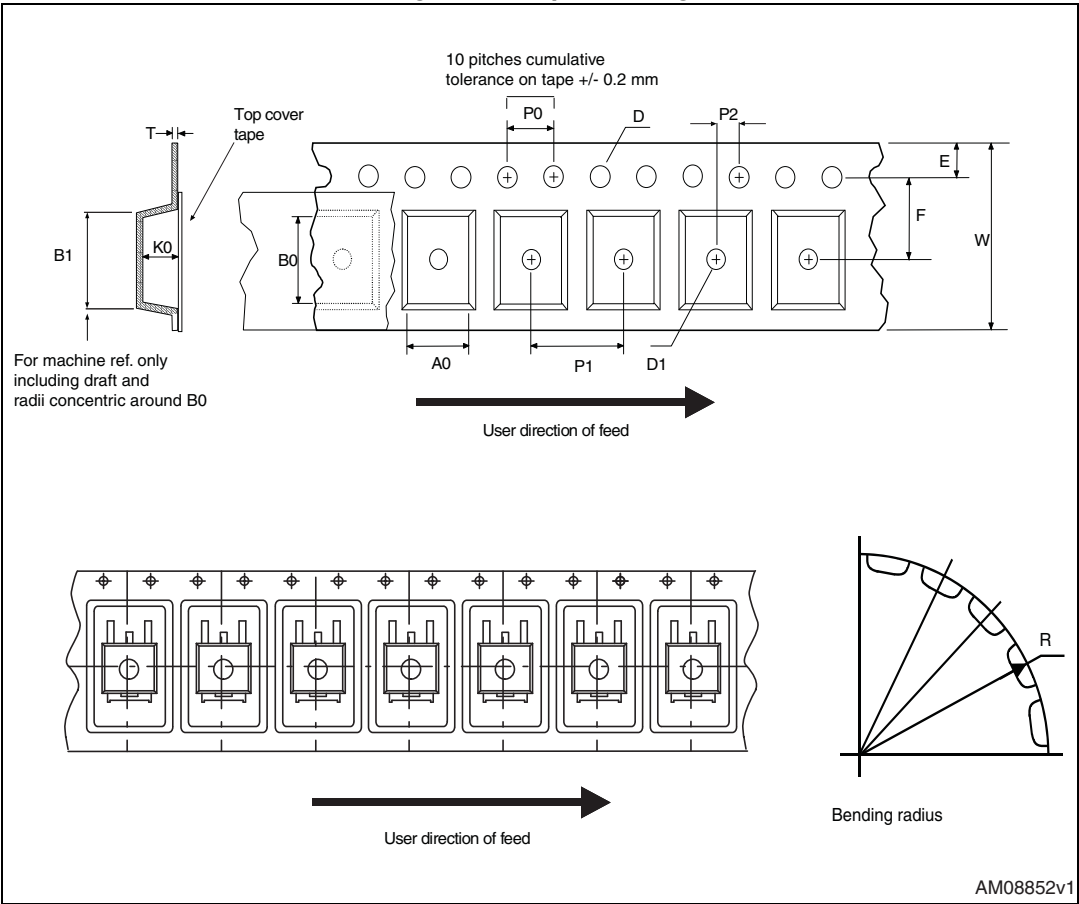
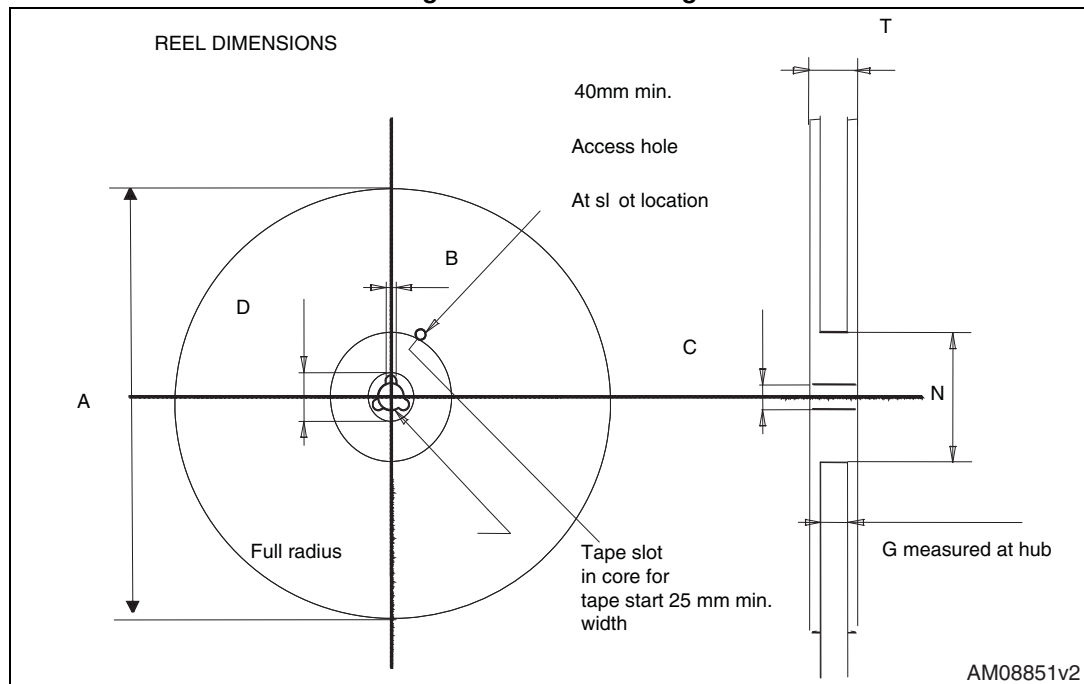


Figure 25. Reel drawing



6 Revision history

Table 11. Document revision history

Date	Revision	Changes
08-Feb-2013	1	Initial release.
24-Jun-2013	2	Added device in D ² PAK. Modified Table 1: Device summary . Added Section 2.1: Electrical characteristics (curves) . Updated Section 4: Package mechanical data and Section 5: Packaging mechanical data . Minor text changes.
25-Sep-2013	3	Updated $t_{d(on)}$ value for resistive load in Table 6: Switching on/off . Updated mechanical data for DPAK. Minor text changes.

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